

IN THE SPECIFICATION

Page 1, immediately after the title, insert as a new paragraph --This application is a divisional of U.S. Patent Application Serial No. 09/917,777, filed July 31, 2001, the entire contents of which are incorporated herein by reference.- -

On page 3, the paragraph beginning at line 17, has been amended as follows:

In order to accomplish the aforementioned and other objects, according to one aspect of the present invention, a semiconductor memory device including at least one transistor ~~in which one bit memory cell is composed of one transistor~~, wherein the transistor comprises: